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ON Semiconductor®

FDMS4D4N08C

N-Channel Shielded Gate PowerTrench[®] MOSFET 80 V, 123 A, 4.3 m Ω

Features

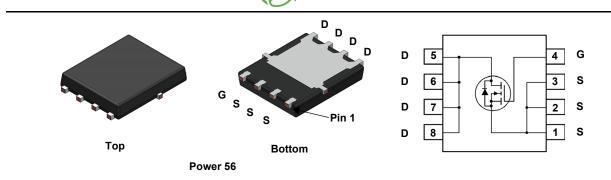
- Shielded Gate MOSFET Technology
- Max r_{DS(on)} = 4.3 mΩ at V_{GS} = 10 V, I_D = 44 A
- Max r_{DS(on)} = 10.4 mΩ at V_{GS} = 6 V, I_D = 22 A
- 50% Lower Qrr than Other MOSFET Suppliers
- Lowers Switching Noise/EMI
- MSL1 Robust Package Design
- 100% UIL Tested
- RoHS Compliant

General Description

This N-Channel MV MOSFET is produced using ON Semiconductor's advanced PowerTrench[®] process that incorporates Shielded Gate technology. This process has been optimized to minimise on-state resistance and yet maintain superior switching performance with best in class soft body diode.

Applications

- Primary DC-DC MOSFET
- Synchronous Rectifier in DC-DC and AC-DC
- Motor Drive
- Solar



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted.

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			80	V	
V _{GS}	Gate to Source Voltage			±20	V	
ID	Drain Current -Continuous	T _C = 25 °C	(Note 5)	123		
	-Continuous	T _C = 100 °C	(Note 5)	78		
	-Continuous	T _A = 25 °C	(Note 1a)	17	Α	
	-Pulsed		(Note 4)	498		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	486	mJ	
P _D	Power Dissipation	T _C = 25 °C		125	W	
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5		
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

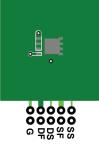
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.0	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1	a) 50	C/vv

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS4D4N08C	FDMS4D4N08C	Power 56	13 "	12 mm	3000 units

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	80			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 µA, referenced to 25 °C		63		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 64 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
On Chara	cteristics			·		
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	2.0	3.0	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-8.2		mV/°C
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 44 A	3.7 4.3			
		$V_{GS} = 6 V, I_D = 22 A$		5.7	10.4	mΩ
		V_{GS} = 10 V, I _D = 44 A, T _J = 125 °C		5.9	7.2	1
g _{FS}	Forward Transconductance	V _{DS} = 5 V, I _D = 44 A		98		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			2920	4090	pF
C _{oss}	Output Capacitance	$-V_{\rm DS} = 40 \text{V}, V_{\rm GS} = 0 \text{V},$		1045	1465	pF
C _{rss}	Reverse Transfer Capacitance	f = 1 MHz		35	50	pF
R _a	Gate Resistance		0.1	1.3	2.5	Ω
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time			17	31	ns
t _r	Rise Time	V _{DD} = 40 V, I _D = 44 A,		7	15	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10 V, R _{GEN} = 6 Ω		25	40	ns
t _f	Fall Time			5	10	ns
Qg	Total Gate Charge	V _{GS} = 0 V to 10 V		40	56	nC
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 6 V V_{DD} = 40 V,$		25	35	nC
Q _{gs}	Gate to Source Charge	I _D = 44 A		13		nC
Q _{gd}	Gate to Drain "Miller" Charge			8		nC
Q _{oss}	Output Charge	V _{DD} = 40 V, V _{GS} = 0 V		60		nC
Q _{sync}	Total Gate Charge Sync.	V _{DS} = 0 V, I _D = 44 A		35		nC
Drain-Soເ	urce Diode Characteristics					
	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.1 A$ (Note 2)		0.7	1.2	
V _{SD}		$V_{GS} = 0 V, I_S = 44 A$ (Note 2)		0.8	1.3	V
t _{rr}	Reverse Recovery Time			26	42	ns
Q _{rr}	Reverse Recovery Charge	– I _F = 22 A, di/dt = 300 A/μs		44	71	nC
t _{rr}	Reverse Recovery Time			20	32	ns
••	Reverse Recovery Charge	I _F = 22 A, di/dt = 1000 A/μs		106	169	nC

Notes: 1. $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta CA}$ is determined by the user's board design.

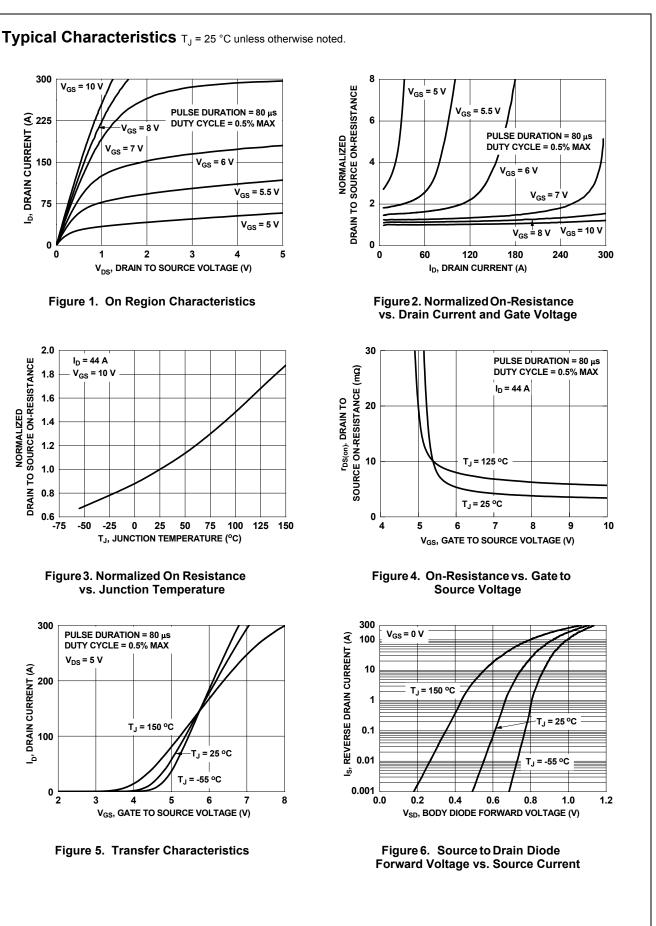


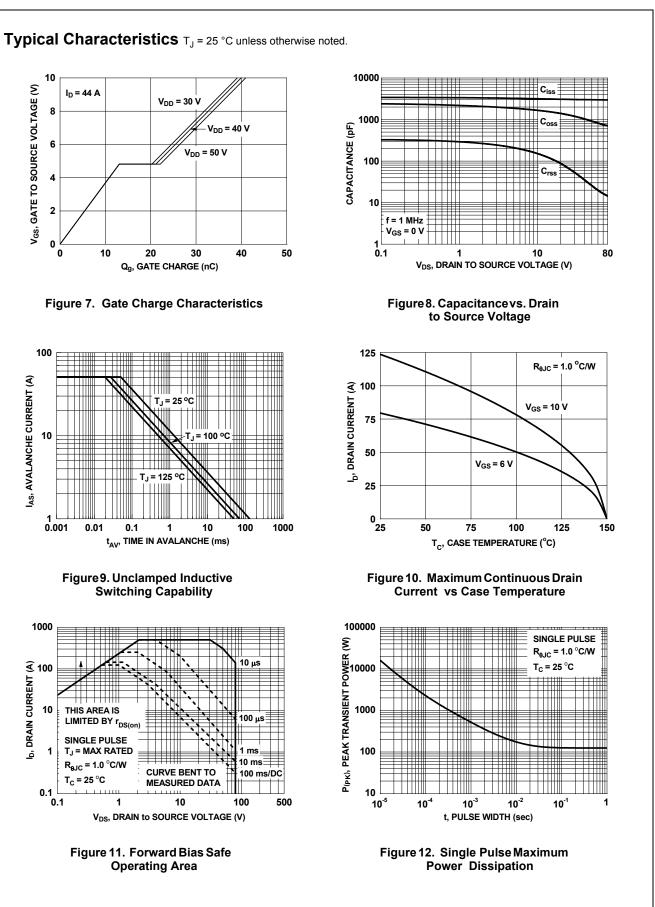
50 °C/W when mounted on a 1 in² pad of 2 oz copper

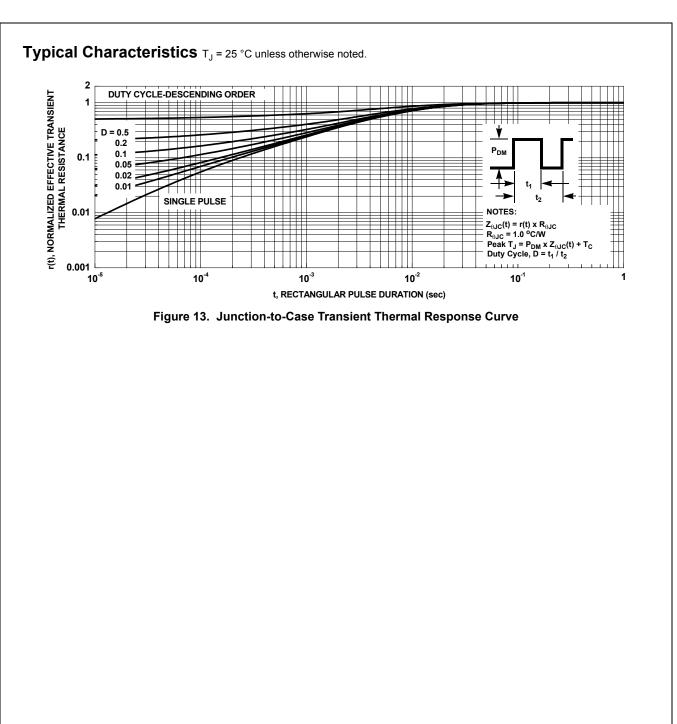


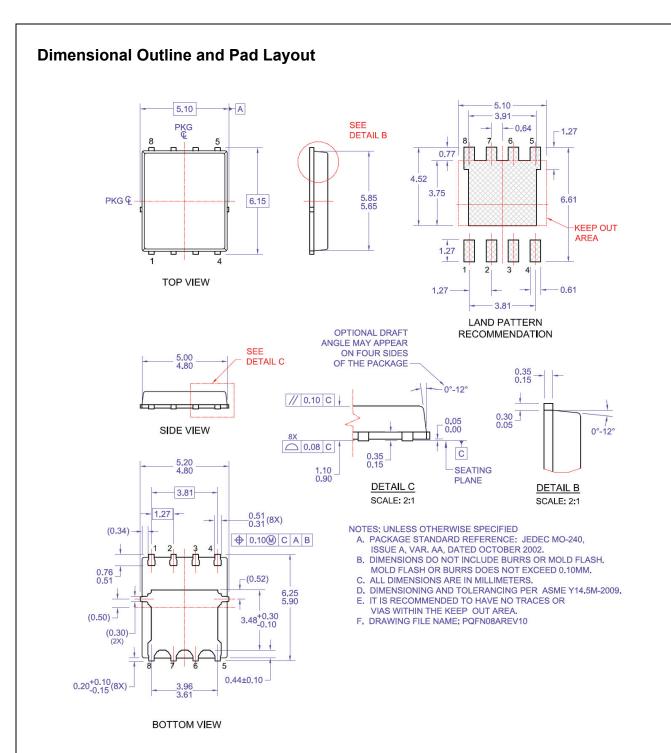
125 °C/W when mounted on a minimum pad of 2 oz copper.

Pulse Test: Pulse Width < 300 μs, Duty cycle < 2.0%.
E_{AS} of 486 mJ is based on starting T_J = 25 °C; N-ch: L = 3 mH, I_{AS} = 18 A, V_{DD} = 80 V, V_{GS} =10 V. 100% test at L = 0.1 mH, I_{AS} = 51 A.
Pulsed Id please refer to Fig 11 SOA graph for more details.
Computed continuous current limited to Max Junction Temperature only, actual continuous current will be limited by thermal & electro-mechanical application board design.





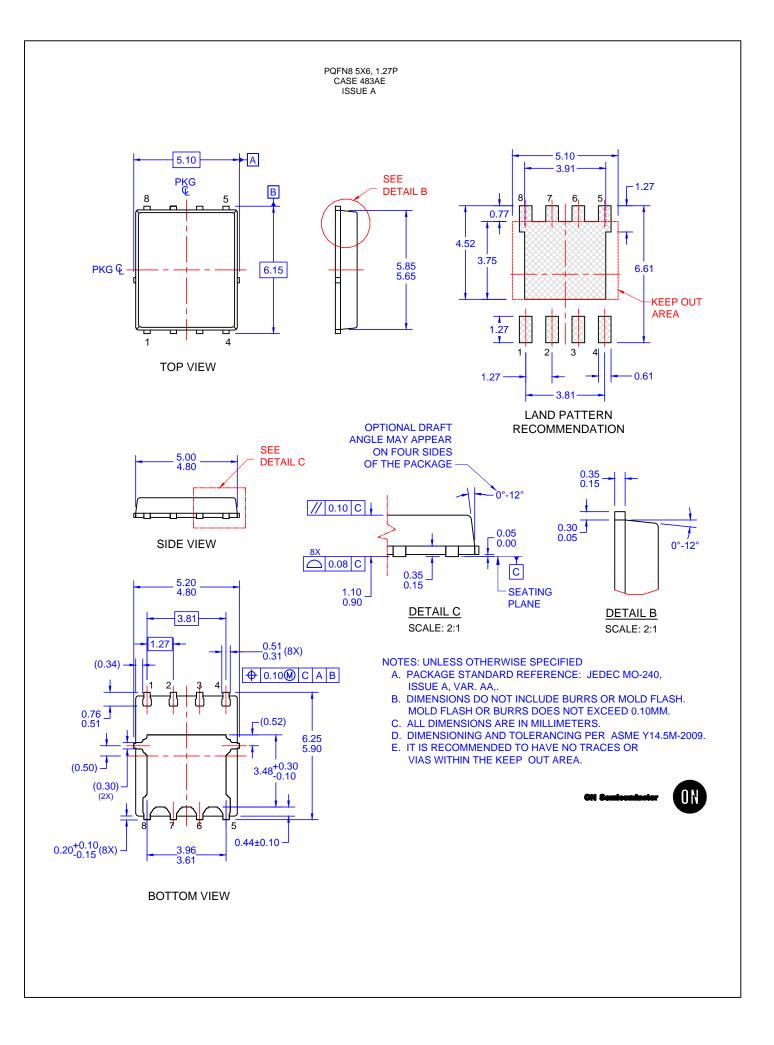




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